

**PROTECTION PRODUCTS**

**Description**

RailClamps are surge rated diode arrays designed to protect high speed data interfaces. The SR series has been specifically designed to protect sensitive components which are connected to data and transmission lines from overvoltage caused by ESD (electrostatic discharge), EFT (electrical fast transients), and tertiary lightning.

The unique design of the SR series devices incorporates four surge rated, low capacitance steering diodes and a TVS diode in a single package. The TVS diode is constructed using Semtech's proprietary low voltage EPD technology for superior electrical characteristics at 3.3 volts.

During transient conditions, the steering diodes direct the transient to either the positive side of the power supply line or to ground. The internal TVS diode prevents over-voltage on the power line, protecting any downstream components.

The low capacitance array configuration allows the user to protect two high-speed data or transmission lines. The low inductance construction minimizes voltage overshoot during high current surges.

**Features**

- ◆ ESD protection to IEC 61000-4-2, Level 4
- ◆ Array of surge rated diodes with internal EPD TVS™ diode
- ◆ Protects two I/O lines
- ◆ Low capacitance (<10pF) for high-speed interfaces
- ◆ Low leakage current (< 1µA)
- ◆ Low operating voltage: 3.3V
- ◆ Solid-state technology

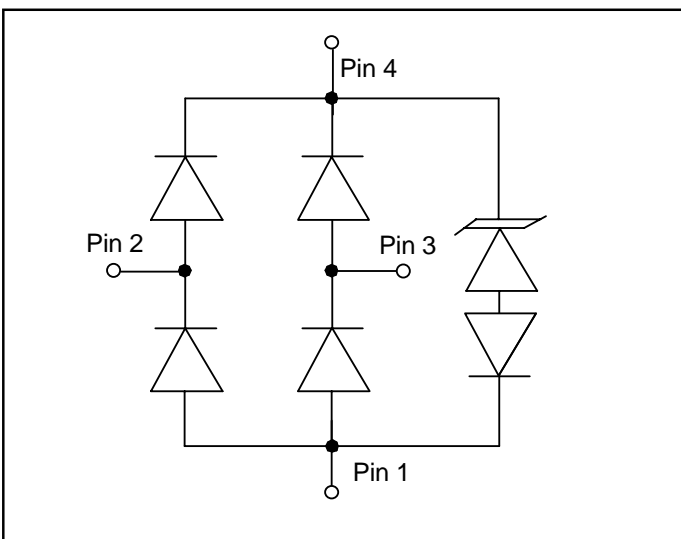
**Mechanical Characteristics**

- ◆ JEDEC SOT-143 package
- ◆ Molding compound flammability rating: UL 94V-0
- ◆ Marking : R3.3
- ◆ Packaging : Tape and Reel per EIA 481

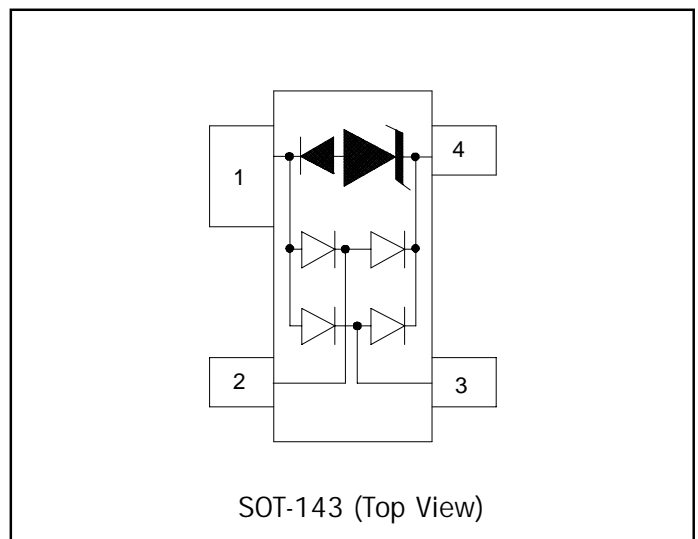
**Applications**

- ◆ Data and I/O lines
- ◆ Sensitive Analog Inputs
- ◆ Video Line Protection
- ◆ Portable Electronics
- ◆ Microcontroller Input Protection
- ◆ WAN/LAN Equipment

**Circuit Diagram**



**Schematic & PIN Configuration**



## Absolute Maximum Rating

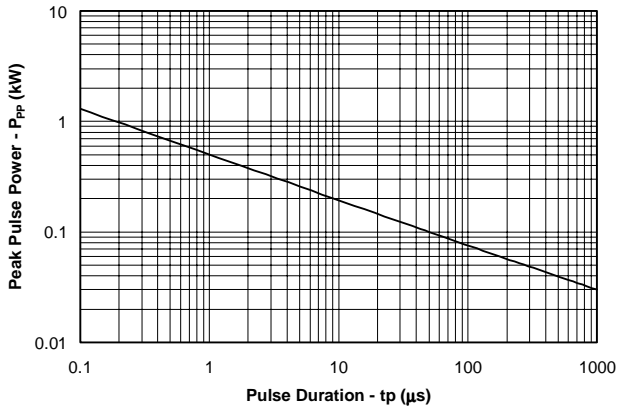
Rating	Symbol	Value	Units
Peak Pulse Power (tp = 8/20μs)	$P_{pk}$	150	Watts
Peak Pulse Current (tp = 8/20μs)	$I_{pp}$	10	A
Peak Forward Voltage ( $I_f = 1A$ , tp=8/20μs)	$V_{FP}$	1.5	V
Lead Soldering Temperature	$T_L$	260 (10 sec.)	°C
Operating Temperature	$T_J$	-55 to +125	°C
Storage Temperature	$T_{STG}$	-55 to +150	°C

## Electrical Characteristics

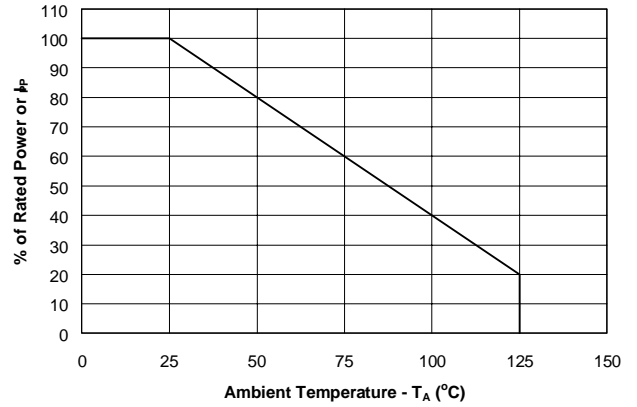
SR3.3						
Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand-Off Voltage	$V_{RWM}$				3.3	V
Punch-Through Voltage	$V_{PT}$	$I_{PT} = 2\mu A$	3.5			V
Snap-Back Voltage	$V_{SB}$	$I_{SB} = 50mA$	2.8			V
Reverse Leakage Current	$I_R$	$V_{RWM} = 3.3V$ , $T=25^\circ C$			1	μA
Clamping Voltage	$V_C$	$I_{PP} = 1A$ , tp = 8/20μs			7	V
Clamping Voltage	$V_C$	$I_{PP} = 10A$ , tp = 8/20μs			15	V
Maximum Peak Pulse Current	$I_{PP}$	tp = 8/20μs			10	A
Junction Capacitance	$C_J$	Between I/O pins and Gnd $V_R = 0V$ , f = 1MHz		6	10	pF
		Between I/O pins $V_R = 0V$ , f = 1MHz		3		pF

Typical Characteristics

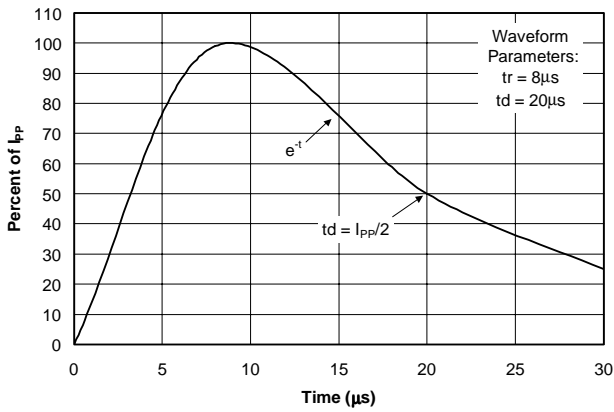
Non-Repetitive Peak Pulse Power vs. Pulse Time



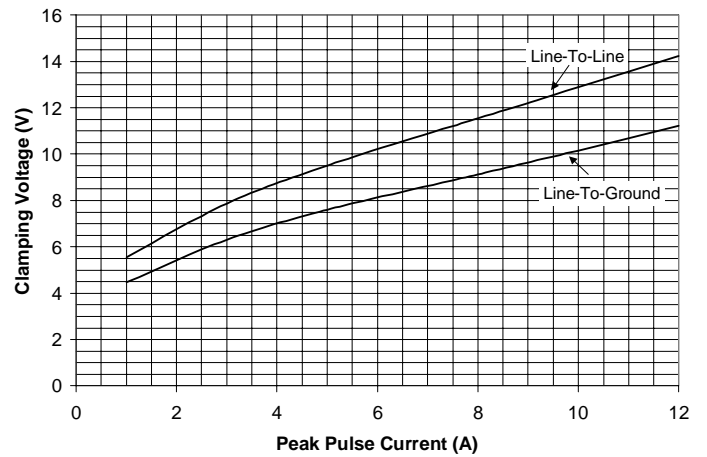
Power Derating Curve



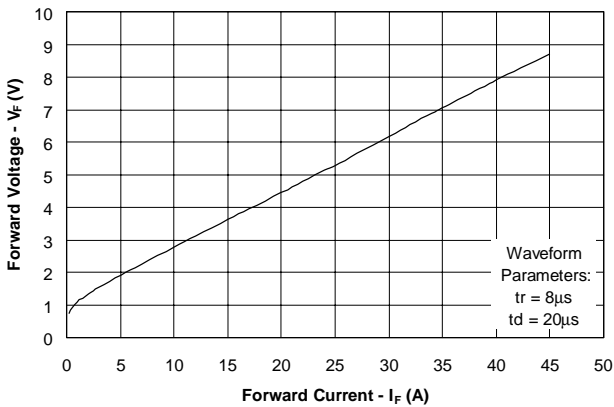
Pulse Waveform



Clamping Voltage vs. Peak Pulse Current



Forward Voltage vs. Forward Current



Applications Information

**Device Connection Options for Protection of Two High-Speed Data Lines**

The SR3.3 TVS is designed to protect two data lines from transient over-voltages by clamping them to a fixed reference. When the voltage on the protected line exceeds the reference voltage (plus diode  $V_F$ ) the steering diodes are forward biased, conducting the transient current away from the sensitive circuitry. Data lines are connected at pins 2 and 3. The negative reference (REF1) is connected at pin 1. This pin should be connected directly to a ground plane on the board for best results. The path length is kept as short as possible to minimize parasitic inductance.

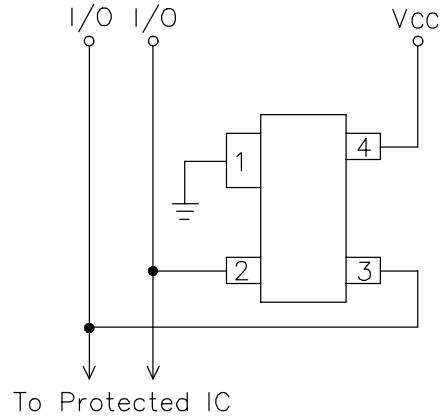
The positive reference (REF2) is connected at pin 4. The options for connecting the positive reference are as follows:

1. To protect data lines and the power line, connect pin 4 directly to the positive supply rail ( $V_{CC}$ ). In this configuration the data lines are referenced to the supply voltage. The internal TVS diode prevents over-voltage on the supply rail.
2. The SR3.3 can be isolated from the power supply by adding a series resistor between pin 4 and  $V_{CC}$ . A value of  $10k\Omega$  is recommended. The internal TVS and steering diodes remain biased, providing the advantage of lower capacitance.
3. In applications where no positive supply reference is available, or complete supply isolation is desired, the internal TVS may be used as the reference. In this case, pin 4 is not connected. The steering diodes will begin to conduct when the voltage on the protected line exceeds the working voltage of the TVS (plus one diode drop).

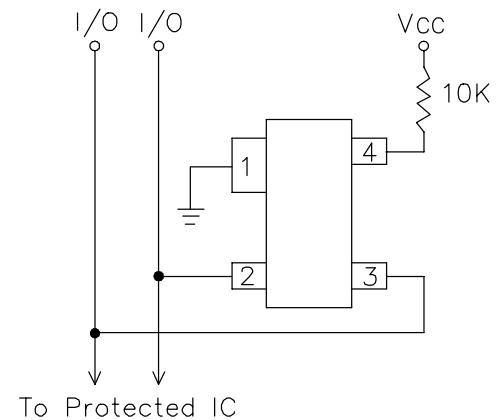
**Board Layout Considerations for ESD Protection**

Board layout plays an important role in the suppression of extremely fast rise-time ESD transients. Recall that the voltage developed across an inductive load is proportional to the time rate of change of current through the load ( $V = L di/dt$ ). The total clamping voltage seen by the protected load will be the sum of

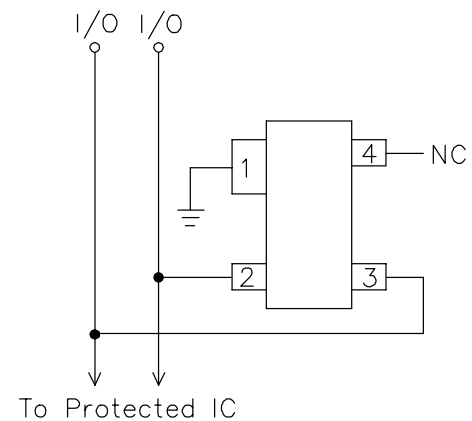
**Data Line and Power Supply Protection Using  $V_{CC}$  as reference**



**Data Line Protection with Bias and Power Supply Isolation Resistor**



**Data Line Protection Using Internal TVS Diode as Reference**



Applications Information (*continued*)

the TVS clamping voltage and the voltage due to the parasitic inductance ( $V_{c(TOT)} = V_c + L di/dt$ ). *Parasitic inductance in the protection path can result in significant voltage overshoot, reducing the effectiveness of the suppression circuit.* An ESD induced transient for example reaches a peak in approximately 1ns. For a 30A pulse (per IEC 61000-4-2 Level 4), 1nH of series inductance will increase the effective clamping voltage by 30V

( $V = 1 \times 10^{-9} (30/1 \times 10^{-9})$ ). For maximum effectiveness, the following board layout guidelines are recommended:

- Minimize the path length between the SR3.3 and the protected line.
- Place the SR3.3 near the RJ45 connector to restrict transient coupling in nearby traces.
- Minimize the path length (inductance) between the RJ45 connector and the SR3.3.

EPD TVS Characteristics

The internal TVS of the SR3.3 is constructed using Semtech's proprietary EPD technology. The structure of the EPD TVS is vastly different from the traditional pn-junction devices. At voltages below 5V, high leakage current and junction capacitance render conventional avalanche technology impractical for most applications. However, by utilizing the EPD technology, the SR3.3 can effectively operate at 3.3V while maintaining excellent electrical characteristics.

The EPD TVS employs a complex npn structure in contrast to the pn structure normally found in traditional silicon-avalanche TVS diodes. The EPD mechanism is achieved by engineering the center region of the device such that the reverse biased junction does not avalanche, but will "punch-through" to a conducting state. This structure results in a device with superior dc electrical parameters at low voltages while maintaining the capability to absorb high transient currents.

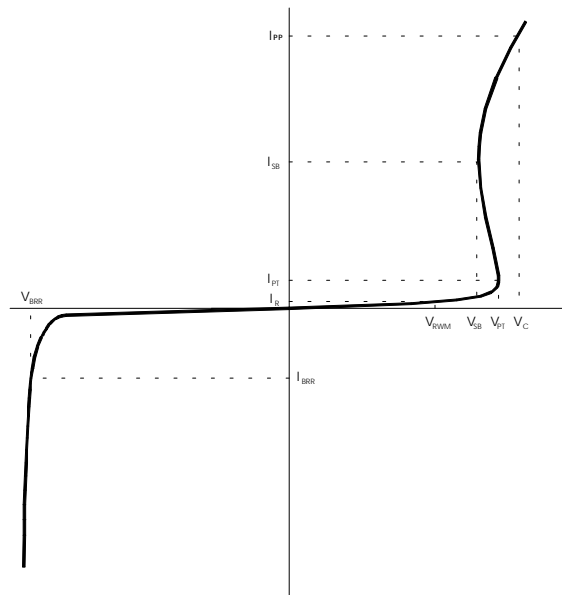
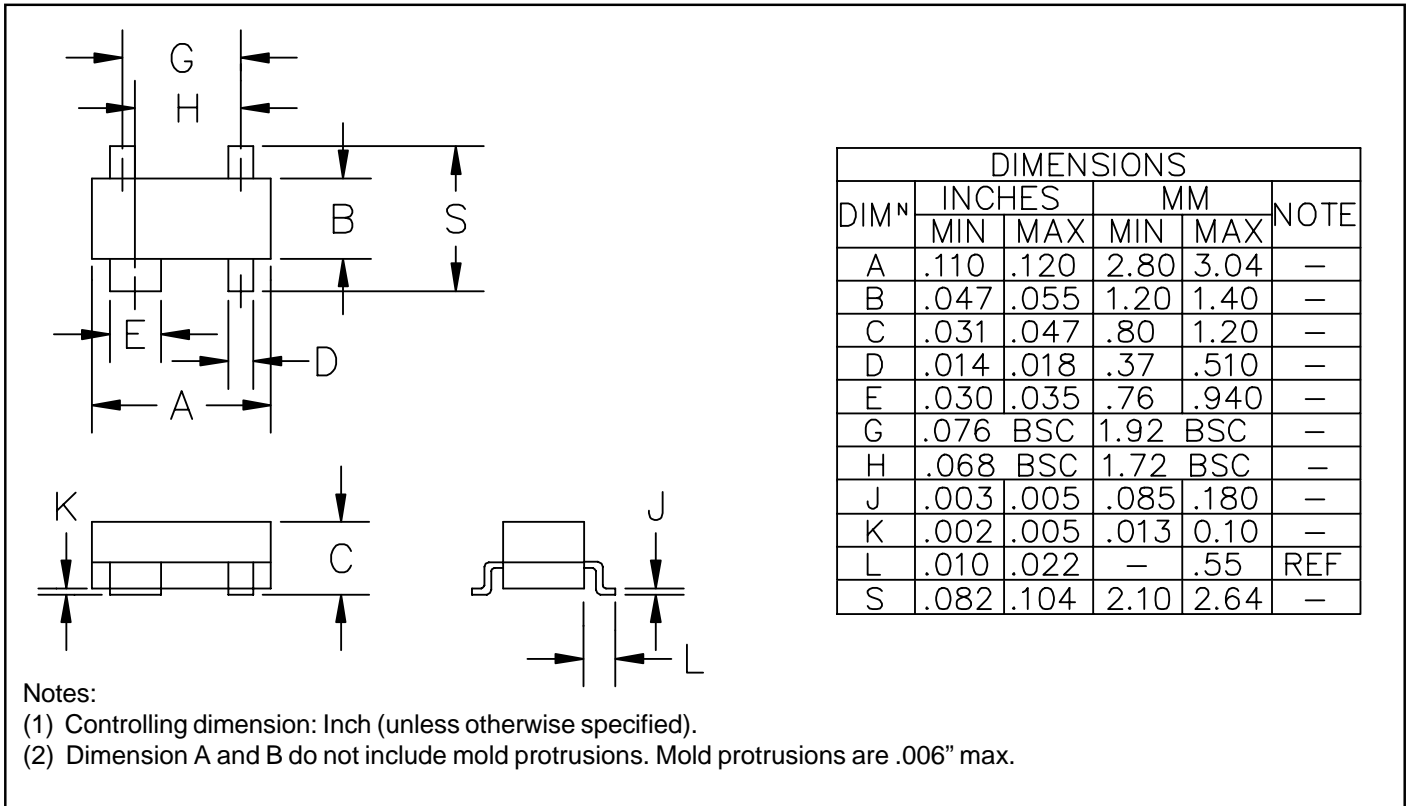


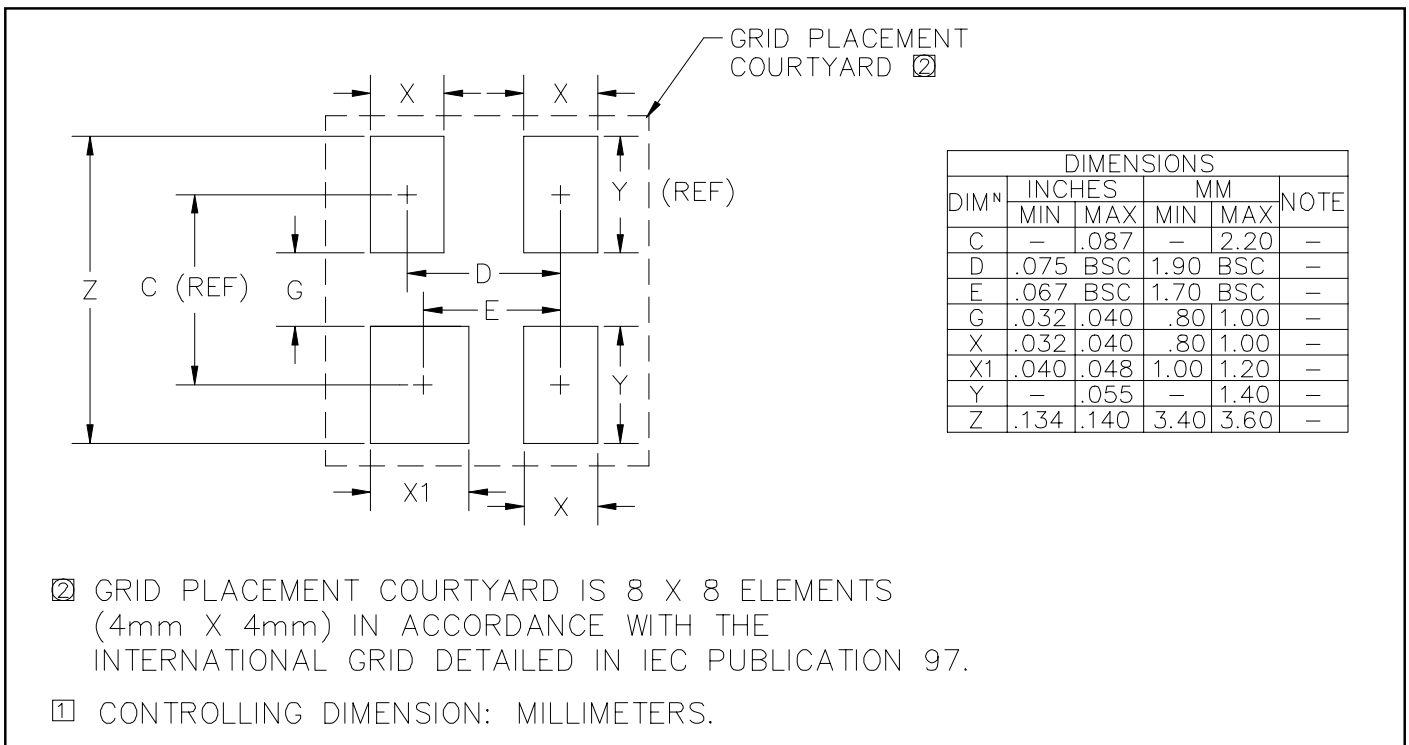
Figure 1 - EPD TVS IV Characteristic Curve

The IV characteristic curve of the EPD device is shown in Figure 1. The device represents a high impedance to the circuit up to the working voltage ( $V_{RWM}$ ). During a transient event, the device will begin to conduct as it is biased in the reverse direction. When the punch-through voltage ( $V_{PT}$ ) is exceeded, the device enters a low impedance state, diverting the transient current away from the protected circuit. When the device is conducting current, it will exhibit a slight "snap-back" or negative resistance characteristic due to its structure. This must be considered when connecting the device to a power supply rail. To return to a non-conducting state, the current through the device must fall below the snap-back current (approximately < 50mA).

Outline Drawing - SOT-143



Land Pattern - SOT-143



## PROTECTION PRODUCTS

PRELIMINARY

## Marking Codes

Part Number	Marking Code
SR3.3	R3.3

## Ordering Information

Part Number	Working Voltage	Qty per Reel	Reel Size
SR3.3.TC	3.3V	3,000	7 Inch
SR3.3.TG	3.3V	10,000	13 Inch

## Contact Information

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